TOSHIBA 2SA1300

TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

2 S A 1 3 0 0

STROBO FLASH APPLICATIONS

MEDIUM POWER AMPLIFIER APPLICATIONS

High DC Current Gain and Excellent her Linearity

: $h_{FE(1)} = 140 \sim 600 \text{ (V}_{CE} = -1 \text{ V, I}_{C} = -0.5 \text{ A})$

: $h_{FE(2)} = 60$ (Min.), 120 (Typ.) ($V_{CE} = -1 V$, $I_{C} = -4 A$)

Low Saturation Voltage

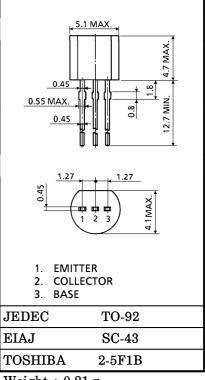
: $V_{CE (sat)} = -0.5 \text{ V (Max.)}$ (IC = -2 A, IB = -50 mA)

MAXIMUM RATINGS (Ta = 25°C)

CHARACT	SYMBOL	RATING	UNIT		
Collector-Base Voltage		v_{CBO}	-20	V	
Collector-Emitter Voltage		VCES	-20	V	
		v_{CEO}	-10		
Emitter-Base Voltage		$V_{ m EBO}$	-6	V	
Collector Current	DC	$I_{\mathbf{C}}$	-2	A	
	Pulsed (Note 1)	I_{CP}	- 5		
Base Current	$I_{\mathbf{B}}$	-0.2	Α		
Collector Power Dissipation		$P_{\mathbf{C}}$	750	mW	
Junction Temperature		$\mathrm{T_{j}}$	150	°C	
Storage Temperature Range		$\mathrm{T_{stg}}$	-55~150	°C	

(Note 1): Pulse Witdth = 10 ms (Max.), Duty Cycle = 30% (Max.)

Unit in mm



Weight: 0.21 g

TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor

TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

The information contained herein is subject to change without notice.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = -20 \text{ V}, I_{E} = 0$	_	_	-0.1	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -6 V, I_{C} = 0$	_	_	-0.1	μ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$	-10	_	_	V
Emitter-Base Breakdown Voltage	V (BR) EBO	$I_{\mathrm{E}}=-1\mathrm{mA},~I_{\mathrm{C}}=0$	-6	_	_	V
DC Current Gain	h _{FE (1)} (Note 2)	$V_{CE} = -1 V, I_{C} = -0.5 A$	140	_	600	
	hFE (2)	$V_{CE} = -1 V, I_{C} = -4 A$	60	120	_	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{\rm C} = -2{\rm A},\ I_{\rm B} = -50{\rm mA}$	_	-0.2	-0.5	V
Base-Emitter Voltage	$ m v_{BE}$	$V_{CE} = -1 V, I_{C} = -2 A$	_	-0.83	-1.5	V
Transition Frequency	$ m f_{T}$	$V_{CE} = -1 \text{ V}, I_{C} = -0.5 \text{ A}$		140		MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10 V, I_{E} = 0,$ f = 1 MHz	_	50	_	рF

(Note 2) : $h_{FE\,(1)}$ Classification Y : 140~280, GR : 200~400, BL : 300~600

